NSN 5961-01-191-3343

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-191-3343 **Inclosure Material:** Plastic **Overall Length:** 0.625 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **End Application:** 6625-01-144-4481 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 6.0 static forward current transfer ratio, common-emitter and 30.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead and 1 unthreaded hole Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-01-191-3343 Transistor - Page 2 of 2



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